

# Revealing the order parameter dynamics of 1T-TiSe<sub>2</sub> following optical excitation

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The formation of a charge density wave state is characterized by an order parameter. The way it is established provides unique information on both the role that correlation plays in driving the charge density wave formation and the mechanism behind its formation. Here we use time and angle resolved photoelectron spectroscopy to optically perturb the charge-density phase in 1T-TiSe<sub>2</sub> and follow the recovery of its order parameter as a function of energy, momentum and excitation density. Our results reveal that two distinct orders contribute to the gap formation, a CDW order and pseudogap-like order, manifested by an overall robustness to optical excitation. A detailed analysis of the magnitude of the the gap as a function of excitation density and delay time reveals the excitonic long-range nature of the CDW gap and the short-range Jahn-Teller character of the pseudogap order. In contrast to the gap, the intensity of the folded Se<sub>4p</sub>\* band can only give access to the excitonic order. These results provide new information into the the long standing debate on the origin of the gap in TiSe<sub>2</sub> and place it in the same context of other quantum materials where a pseudogap phase appears to be a precursor of long-range order.

Charge-density waves (CDW) are states of broken symmetry characterized by a complex order parameter defined by both phase and amplitude, where the latter is proportional to the energy gap<sup>1</sup>. In the simplest approximation they can be described by a mean-field theory of a one-dimensional electron–lattice system in the weak-coupling limit<sup>1,2</sup> which leads to a large coherence length. Note that the term coherence length, which will be used in this work analogously to classical CDW literature<sup>1,3</sup>, corresponds to the spatial dimension of electron-electron or electron-hole pairs<sup>1</sup>. In contrast to weak coupling, within the strong coupling limit the coherence length becomes short and the system can be described best within a local bonding picture. As a consequence, in the strong coupling limit only the long-range order of the CDW is lost above the transition temperature but fluctuating short-range order remains<sup>2,3</sup>. In other words, amplitude and phase coherence become disentangled and a gap in the electronic spectra, a pseudogap, appears well before the long-range charge density wave order sets in. In this pseudogap phase short-ranged CDW fluctuations with a well defined amplitude are still present. We note that this phase is different from the high symmetry phase predicted to exist at high temperature where the system is semi-metallic with a negative gap<sup>4-6</sup>. This behavior bears analogies to the case of unconventional superconductors<sup>7,8</sup>.

Among the various CDW materials, 1T-TiSe<sub>2</sub> holds a special place given the presence of a) a broad variety of many body interactions, such as electron-electron, electron-hole and electron-lattice interactions, leading to excitonic condensation<sup>9,10</sup> and phonon softening<sup>11,12</sup> b) of superconductivity induced via pressure<sup>13,14</sup> or doping<sup>15</sup>, both of which lead to a breaking of the CDW long-range order; and c) CDW fluctua-

tions above the transition temperature, suggestive of a strong coupling regime and short coherence length<sup>2,11,16</sup>.

The key to study this intriguing interplay of long- and short-range order and to understand the emergence of such correlated behavior is the order parameter. Indeed, having direct access to the quenching and re-formation dynamics of the order parameter during a photoinduced phase transition retains unique information on the mechanism behind the establishment of the new order. In this regard, time- and angle-resolved photoemission spectroscopy (tr-ARPES) yields a powerful way to access the formation and dynamics of the gap, given that it is the only technique that can directly monitor the onset of the order parameter with simultaneous momentum and time resolution. While signatures of the gap in the optical conductivity<sup>17</sup> as well as the dynamics of the valence band at the  $\Gamma$  point<sup>18,19</sup> have been studied before, in this study we directly follow the actual gap dynamics while also providing a direct comparison with all other relevant quantities, namely excited carriers and backfolded Se<sub>4p</sub>\* band. We find that following photoexcitation, the gap undergoes only a partial quenching, up to 30%, of its equilibrium value ( $\sim 130$  meV). This points to the existence of a pseudogap and to the presence of multiple coexisting mechanisms contributing to the CDW formation in TiSe<sub>2</sub>. Finally we reveal that the folded Se<sub>4p</sub>\* is mostly connected to only one of the components cautioning the common assumption that spectral weight dynamics is directly related to order parameter dynamics.

Figure 1 shows the dynamics of the electronic band structure along the high symmetry direction  $\Gamma$ - $M$ - $\Gamma$  for a temperature of 80 K, i.e. below the CDW transition.

Data are taken for a probe energy of 22.3 eV with pump excitation of 780 nm ( $\sim 1.6$  eV) and a fluence of 80  $\mu\text{J}/\text{cm}^2$ . The

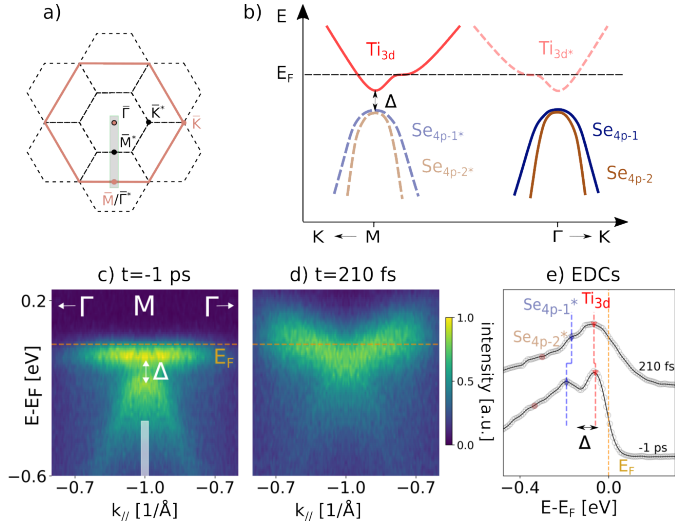


FIG. 1. a) First BZ in the high symmetry (orange) and CDW phase (black); the grey bar illustrates the cuts measured in the ARPES spectra in  $\Gamma$ - $M$ - $\Gamma$  direction. b) Schematic bandstructure of the CDW state (adapted from<sup>5</sup>). c) and d) ARPES spectra of the  $M$ -point in equilibrium (c) and after excitation with 780 nm pump pulses at  $80 \mu\text{J}/\text{cm}^2$  fluence (d). For clarity the spectra are mirrored at the  $M$  point. The Fermi level is indicated by the dashed orange line. e) EDCs taken at  $M$  corresponding to the spectra in panel c and d. The region in momentum space over which the EDCs were integrated is shown by the white box in panel c. Markers indicate the fitted peak positions of the  $\text{Ti}_{3d}$  conduction band (red triangle) as well as the  $\text{Se}_{4p-1}$  (blue diamonds) and  $\text{Se}_{4p-2}$  valence bands (brown circles). Circles represent raw data and solid black lines represent the smoothed raw data using the Gaussian method (10 meV window).

repetition rate is 25 KHz and the overall temporal resolution is  $\sim 65$  fs. More details of the XUV-trARPES setup can be found in the Methods section of the Supplementary Material as well as in<sup>20,21</sup>.

Note that the probe energy of 22.3 eV allows access to states close to  $A$  and  $L$  point within the bulk Brillouin zone notation<sup>22</sup>. However, for consistency with previous trARPES work<sup>23,24</sup>, we will use the surface BZ notation and refer to these points as the  $\Gamma$  and  $M$  point<sup>25</sup>. Panel a shows the 2D Brillouin zone (BZ) in the high symmetry (orange) and CDW (black) state. When going through the phase transition, the unit cell size doubles from a  $(1 \times 1 \times 1)$  structure at room temperature to a  $(2 \times 2 \times 2)$  superstructure below  $\sim 200$  K<sup>26</sup>. Panel b displays the schematic band structure<sup>5</sup> in the CDW phase along the high symmetry directions. It shows the bands from  $\text{Ti}_{3d}$  to  $\text{Se}_{4p}$  orbitals. As widely discussed in the literature<sup>2,27-30</sup>, the fingerprints of the CDW state are the backfolding of the spin-orbit split  $\text{Se}_{4p}$  bands at  $\Gamma$  ( $\text{Se}_{4p-1}$  and  $\text{Se}_{4p-2}$ , see solid line in panel b) onto the  $M$  point ( $\text{Se}_{4p-1}^*$  and  $\text{Se}_{4p-2}^*$ , see dashed line in panel b) and the opening of a gap. Panel c shows the measured equilibrium band structure measured along the  $\Gamma$ - $M$ - $\Gamma$  direction (location of the cut in the Brillouin zone is indicated by the grey box in panel a), where both the backfolded  $\text{Se}_{4p-1}^*$  and  $\text{Se}_{4p-2}^*$  valence band are visible. Additionally we can resolve the bottom of the  $\text{Ti}_{3d}$

conduction band and hence access the gap formed between the lowest  $\text{Ti}_{3d}$  and the highest  $\text{Se}_{4p}^*$  band. Panel d shows the evolution of these bands following  $\text{Se}_{4p}^*$  pump excitation, revealing three key features. First, the the  $\text{Ti}_{3d}$  parabolic band at  $M$  point is occupied by hot electrons. Moreover, we observe a fast reduction of the gap size between the  $\text{Ti}_{3d}$  and  $\text{Se}_{4p-1}^*$  states. Finally the intensity of the  $\text{Se}_{4p-1}^*$  backfolded band is reduced along with the the quenching of the gap.

The combination of, compared to previous XUV-trARPES work<sup>23,29,31-33</sup>, higher energy resolution ( $< 80$  meV) and access to lower pump fluences of this study allows us for the first time to access the gap dynamics following optical excitation. In panel e of Figure 1, we present raw energy distribution curves (EDCs) at  $M$  point measured along  $\Gamma$ - $M$ - $\Gamma$ -direction (the region in momentum space over which the EDCs were integrated is indicated by the white box in panel c) corresponding to the two spectra shown in panel c and d. In equilibrium we clearly resolve two peaks in the raw spectra corresponding to the top of  $\text{Se}_{4p}^*$  valence band and the bottom of  $\text{Ti}_{3d}$  conduction bands. The distance between the two peaks defines the energy gap. The lower, spin split  $\text{Se}_{4p-2}^*$  band is also resolved in the raw spectra as a weak shoulder. After 210 fs the three bands are still visible, however excited carriers and the melting of the  $\text{Se}_{4p}^*$  band make the gap, despite being still open, less well defined. To extract the gap size and its time evolution, the EDCs spectra were fitted with a function using three peaks of Voigt lineshape to account for the  $\text{Ti}_{3d}$  as well as the two spin splitted  $\text{Se}_{4p}^*$  bands. Details of the fitting procedure are given in Supplementary Note 3. The fitted peak positions are marked in panel e, where red, blue and brown symbols correspond, respectively, to the  $\text{Ti}_{3d}$ ,  $\text{Se}_{4p-1}^*$  and  $\text{Se}_{4p-2}^*$  band.

To study in detail the response of the gap to optical excitation, in Figure 2 we present the fluence dependence of the gap and its dynamics. Panels a and b show EDCs taken at different delay times at  $M$  point after excitation with 80 (panel a) and  $55 \mu\text{J}/\text{cm}^2$  (panel b) to show the temporal evolution of the gap. Note that the slightly different shape of the EDCs in equilibrium is due to the fact that a different batch of samples was used (see Methods section in the Supplementary Material). While in panel b the gap remains clearly visible over all delay times, the pronounced melting of the backfolded  $\text{Se}_{4p}^*$  band in panel a obscures its exact peak position for intermediate delay times ( $\sim 250$ - $550$  fs). Despite this difficulty, we can still extract the gap size with high precision as our XUV light source allowed us to simultaneously monitor the dynamics of the  $\text{Se}_{4p}$  band at  $\Gamma$  point (see Supplementary Note 3). In panel c we plot the change of the gap size as a function of delay time for various fluences, referenced to the equilibrium gap size of  $132 \pm 3$  meV. For reference we also plot the gap size at room temperature (74 meV<sup>22</sup>) (dotted orange line). Additional gap data after excitation with a fluence of  $78 \mu\text{J}/\text{cm}^2$  is shown in Supplementary Note 4. A remarkable fact is that the gap consistently only gets quenched about a fraction of its equilibrium value. This is further confirmed by the gap extracted from spectra taken along  $K$ - $M$ - $K$  direction (see Supplementary Note 4).

Panel d shows the fluence dependence of the relative gap

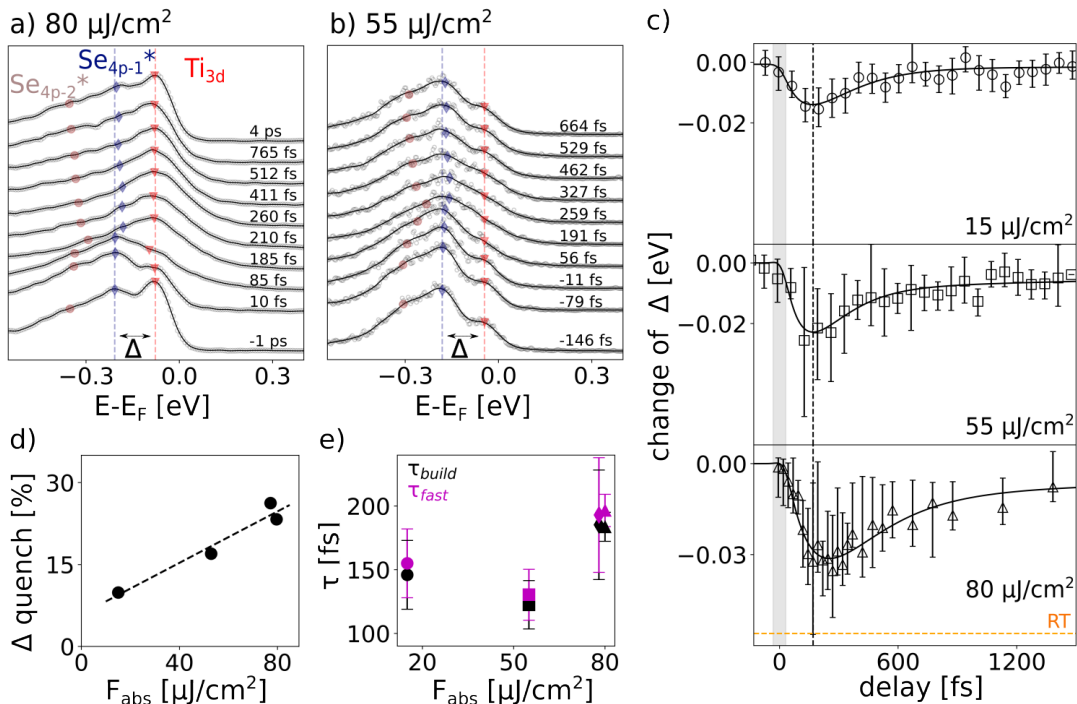


FIG. 2. Gap Dynamics at different excitation density. a-b) Selected EDCs taken at  $M$  point with markers indicating the fitted peak positions of the  $Ti_{3d}$  conduction band (red triangle) and the  $Se_{4p-1}$  (blue diamonds) and  $Se_{4p-2}$  valence bands (brown circles) after excitation with 80 (panel a) and  $55 \mu J/cm^2$  (panel b), respectively. Circles represents raw data and solid black lines represent the smoothed raw data using the Gaussian method (10 meV window). (c) Fitted change of gap size over delay after excitation with 15, 55 and  $80 \mu J/cm^2$ . Solid black lines represent fits to the data. The dotted orange line represents the gap size extracted by equilibrium ARPES at room temperature<sup>22</sup>. d) Maximum gap quench (with respect to the equilibrium value) in dependence of absorbed fluence  $F_{abs}$ . Dashed line is a linear fit of the data points. e) Fitting parameters  $\tau_{build}$  and  $\tau_{fast}$  in dependence of the absorbed fluence.

quench. The data can be appropriately described by a linear fit. However we note that this relationship only holds for the intermediate fluence regime studied in this work. Further studies are needed to elucidate the behavior at very low fluences. For the highest fluences studied, the gap gets quenched only about  $<30\%$  of its equilibrium value. This is a surprising result, as for these fluences, which are well above the reported critical fluence for a complete destruction of the excitonic condensate<sup>17</sup> of  $40 \mu J/cm^2$ , X-ray diffraction experiments<sup>34-36</sup> found a considerable, almost complete, suppression of the structural long-range order. Moreover in our experiment the electronic temperature reaches about 1000 K (as extracted from the Fermi level broadening), which is considerably over the equilibrium transition temperature of 200 K. This robustness of the gap to optical excitation contrasts with various theoretical calculations, which consistently predict the high symmetry phase of  $TiSe_2$  to be semi-metallic<sup>4-6,37</sup>. At the same time this robustness is analogous to ultrafast THz<sup>17</sup> and equilibrium ARPES studies<sup>22,25,27</sup>, where the gap remains open at high excitation densities and temperatures, and is reminiscent of a pseudogap behavior where, even at very high excitation fluences (or temperatures above the transition temperature) the gap is only partially affected<sup>7,8,38</sup>. Finally this observation clearly suggests that the CDW phase in  $TiSe_2$  differs from the behavior of other CDW systems<sup>31,39-41</sup> and super-

conductors<sup>38,42,43</sup> where the order parameter can be optically fully quenched.

Besides the extent of the gap quench additional information on the gap formation mechanism can be obtained by studying the dynamical behavior of the gap. To analyse the dynamics, we fit the data in panel c with the sum of three exponential functions, where one exponential accounts for the quench time, one for a fast and one for a slow recovery component (see Supplementary Note 5). In the following, we refer to the time where the photoinduced change reaches its maximum, as the build up time  $t_{build}$ <sup>29,44</sup>. The extracted fitting parameters, describing the characteristic timescales for the buildup time ( $\tau_{build}$ ) as well as the short ( $\tau_{fast}$ ) relaxation times are shown in Figure 2e. At low fluences the gap dynamics is dominated by a fast femtosecond relaxation process and, as the excitation strength increases, a slower component becomes more dominant for the gap dynamics extracted along  $\Gamma-M-\Gamma$  direction. As a consequence of this slow recovery dynamics, full reopening of the gap occurs on an extended multi picosecond timescale. Furthermore, there is overall only a weak fluence dependence for  $\tau_{build}$  and  $\tau_{fast}$ , with a slight increase with increasing fluence. A similar behavior was observed studying the dynamics of only the  $Se_{4p}$  valence band at  $\Gamma$  point<sup>18,19</sup>. The partial quenching of the gap Figure 2 suggests the presence of two different processes governing the recovery of

the CDW phase; the impeded recovery after strong excitation might be explained by a phonon bottleneck mechanism<sup>18</sup> or to the slow re-establishment of long range coherence because of the inhomogeneous pseudogap state, photoinduced defects<sup>45</sup> and potentially a dimensional crossover<sup>36</sup>.

To shed light into the gap formation mechanism, we compare the gap dynamics with the fluence dependent temporal behavior of the  $\text{Se}_{4p}^*$  band and the excited carriers right above the Fermi level and extent the line of previous XUV measurements<sup>23,29</sup> into the low fluence regime. To extract the dynamics, we integrate the photoemission counts in the red box and the blue box of Figure 3a as the intensity measure of the excited carriers and folded  $\text{Se}_{4p}^*$  bands, respectively. A detailed discussion for the choice of this particular integration region of the excited carriers can be found in Supplementary Note 7. Panel b in Figure 3 shows the excited carrier dynamics at different excitation fluences and panel c the corresponding intensity curves of the  $\text{Se}_{4p}^*$  band. All curves are normalized and show the relative change in spectral weight following optical excitation (see Supplementary Note 1 for the normalization method and details on the background subtraction). To quantitatively analyze these intensity dynamics, we apply the same fitting method as we described for analyzing the gap dynamics in Figure 2.

Notably, the higher the absorbed fluence, the more the  $\text{Se}_{4p}^*$  band gets quenched (panel c) and the more free carriers get excited (panel b). Interestingly, for the same fluence the  $\text{Se}_{4p}^*$  band gets clearly more quenched than the gap (Figure 2d). For a detailed quantitative comparison, in panel d we put the relative gap quench in direct relation to the  $\text{Se}_{4p}^*$  quench. It shows that consistently the extent to which the gap gets quenched is considerably lower than how much the  $\text{Se}_{4p}^*$  intensity gets quenched. Interestingly, when assuming that only the part of the gap that can get quenched by temperature, i.e.  $\Delta_0 \sim 130 \text{ meV} - 74 \text{ meV} = 56 \text{ meV}$ , with 74 meV being the gap size at room temperature<sup>22,25</sup>, is the "real" equilibrium gap, then the new relative quenches (shown in green) of the gap size is considerably closer to a 1:1 relationship (magenta line) with the relative quenches of the  $\text{Se}_{4p}^*$  intensity. This is a strong indication that the majority of the spectral weight of the  $\text{Se}_{4p}^*$  band is connected to only a part of the gap (the part that gets more easily quenched) and thus have the same origin, whereas another contribution to the gap exists that is less pronounced in the  $\text{Se}_{4p}^*$  replica band intensity. We note that within the studied fluence range we do not observe a complete quench of the  $\text{Se}_{4p}^*$  band; the highest quench observed is  $\sim 60\%$  at  $80 \mu\text{J}/\text{cm}^2$ , which is above the reported threshold fluence of  $40 \mu\text{J}/\text{cm}^2$  for a complete destruction of the excitonic condensate<sup>17</sup>. On the one hand a precise comparison of absorbed fluences is difficult, hence it might be possible that even our highest fluence studied is still below the threshold fluence, on the other hand the residual intensity might be caused by the pseudogap-like contribution, which is less pronounced than in the gap.

For a further analysis we directly compare the dynamics of  $\text{Se}_{4p}^*$  band, gap and excited carriers for two selected fluences in panel a of Figure 4. While an excellent correlation between excited carriers and gap dynamics up to  $\sim 500 \text{ fs}$  is observed

for all fluences studied (see Supplementary Note 6), the  $\text{Se}_{4p}^*$  photoinduced intensity changes seem to indicate a much slower initial recovery dynamics. To quantify these findings, in panel b-d we show the fitted parameters for both gap, excited carriers and  $\text{Se}_{4p}^*$  intensity for different fluences. Similarly to the gap (Figure 2c) two different recovery dynamics are identified for each of these curves, leading to a short ( $\tau_{\text{fast}}$ ) and a long ( $\tau_{\text{slow}}$ ) relaxation timescale, in addition to the buildup time ( $\tau_{\text{build}}$ ). As qualitatively seen in panel a, the data in panel b and c reveal overall similar timescales for the gap and the excited carriers for both the buildup time  $\tau_{\text{build}}$  and the initial recovery  $\tau_{\text{fast}}$ . The similarity in buildup time  $\tau_{\text{build}}$  between gap and hot electrons is in favor of an CDW phase that is directly driven by electronic effects. Indeed, as most electrons get photoexcited to  $\sim 0.6 \text{ eV}$  above  $E_F$  (see Supplementary Note 6), carriers accumulating right above the Fermi level are mostly electrons that have scattered down from higher energy levels or electrons that got created in a carrier multiplication process<sup>23,46</sup>, indicating a strong and direct connection between the decreasing of the order parameter and the scattering rate of excited carriers. In contrast, if the quench of the gap was driven by the lattice, one would expect a delay in the response of the gap compared to the build up time of the excited carriers. Accordingly, a recent ultrafast electron diffuse scattering (UEDS) study found that the free carriers created by optical excitation are not strongly coupled to the phonon modes in  $\text{TiSe}_2$ <sup>12</sup>.

Compared to gap and excited carriers the build up time and especially the initial recovery dynamics of the  $\text{Se}_{4p}^*$  intensity is by inspection of panel a seemingly much slower. This is reflected in the values of  $\tau_{\text{build}}$  and  $\tau_{\text{fast}}$  in panel b and c. Furthermore, the three quantities differ by how pronounced the long term component with respect to the fast component is, i.e. the value of  $a_{\text{slow}}/a_{\text{fast}}$ , as plotted in panel d. While the excited carriers do not show a slow component at all and go back to their equilibrium value within  $\sim 1 \text{ ps}$ ,  $\tau_{\text{slow}}$  clearly influences the gap dynamics and is the most pronounced in the  $\text{Se}_{4p}^*$  band dynamics. Note that within our fitting model both  $\tau_{\text{fast}}$  and  $a_{\text{slow}}/a_{\text{fast}}$  modulate the initial recovery between  $\sim 150\text{-}600 \text{ fs}$ , the range in which the differences between gap and  $\text{Se}_{4p}^*$  intensity dynamics are the clearest, and one cannot unambiguously determine if the fast or slow recovery contribution is more responsible for the observed differences. Nevertheless, while Figure 3d implies that the part of the gap that is more easily quenchable and the majority of the  $\text{Se}_{4p}^*$  intensity are predominantly of the same origin, our detailed analysis hints towards subtle differences in the dynamics between both quantities. Unfortunately, to the best of our knowledge their interplay has not been studied yet, neither experimentally nor theoretically, and therefore further investigation is necessary to further clarify the exact relationship between these two spectral fingerprints of the CDW state and to check if the observed differences are a real effect.

The ability to directly access the gap and its dynamic has allowed us to reveal an intriguing unconventional CDW state

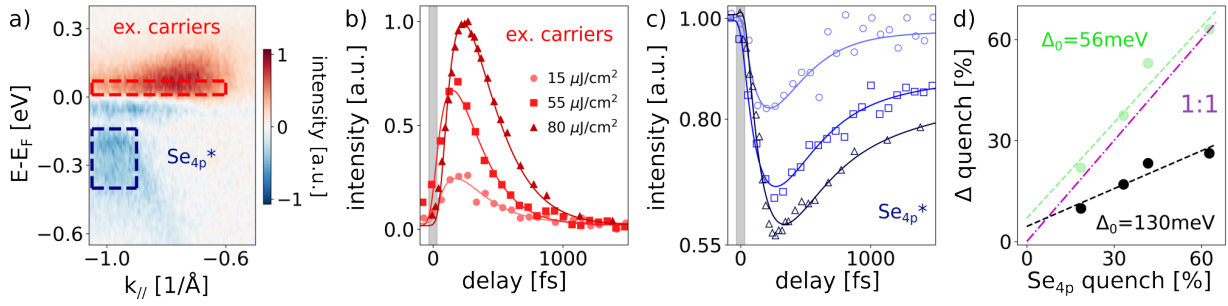


FIG. 3. a) Difference spectrum between a delay of -1 ps and 185 fs after excitation with  $80 \mu\text{J}/\text{cm}^2$  at 80 K. b) Integrated intensity of excited carriers right above the Fermi level (integration region shown by red box in panel a) after excitation with different fluences. Solid lines represent fits to the data points. c) Integrated intensity of  $\text{Se}_{4p}^*$  band (integration region shown by blue box in panel a) after excitation with different fluences. d) Maximum relative gap quench with respect to its equilibrium size in dependence of the maximum quench of the  $\text{Se}_{4p}^*$  intensity. Green data points show the relative gap quench relative to a reference gap size  $\Delta_0$  of 56 meV. Dashed lines are linear fits to the data points. Magenta line shows a 1:1 relationship for comparison.

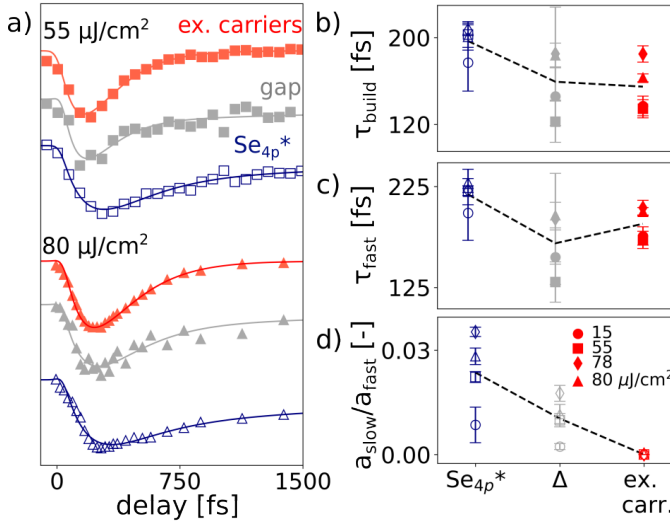


FIG. 4. a) Comparison of the dynamics of  $\text{Se}_{4p}^*$  intensity (blue empty markers), excited carriers (red solid markers) and gap (grey solid markers) for two selected fluences. For clarity the excited carrier dynamics is flipped upside down. b-d) Extracted fitting parameters  $\tau_{\text{build}}$  (b),  $\tau_{\text{fast}}$  (c) and  $a_{\text{slow}}/a_{\text{fast}}$  (d) of excited carriers,  $\text{Se}_{4p}^*$  band intensity and gap for various fluences. Black dashed lines connect the values averaged over all fluences and serve as guide to the eye.

in  $\text{TiSe}_2$ , where two different orders contribute to the gap, one which is easily quenched and a one more robust to photoexcitation. In this regard the sum of our experimental observations allows us to propose a coherent microscopic interpretation of these two order parameters. We first focus on the origin of the part that gets quenched, which we argue to display mostly excitonic order due to multiple reasons. First, the correlation of the buildup time  $\tau_{\text{build}}$  (as shown in Figure 4) between gap and hot electrons is strongly in favor of an electronically driven CDW state. As argued above, the similarities in buildup time indicate a strong and direct connection between the decrease of the order parameter and the scattering rate of

excited carriers. This can be interpreted as the destruction of an excitonic insulator state, where the driving force is the transfer of kinetic energy into the excitonic condensate<sup>46,47</sup>. Second, we established a direct connection between the quenched part of the gap and the backfolded  $\text{Se}_{4p}^*$  band intensity (Figure 3d). Previous trARPES studies focusing on the latter found that it displays behavior characteristic for the excitonic insulator, namely a strongly fluence dependent melting time<sup>29</sup>. Moreover, it was argued that the high intensity of the backfolded band itself in equilibrium can already only be explained within the excitonic insulator scenario<sup>48</sup>. In contrast, we propose that the gap component that cannot be quenched is a signature of an order parameter with short coherence length, which transfers into a pseudogap state with short range CDW fluctuations after optical excitation and that exhibits mostly Jahn-Teller character. The short correlation length associated with this pseudogap phase is in agreement with the reported loss of coherence after optical excitation in a recent ultrafast electron diffraction (UED) experiment<sup>36</sup>, and is confirmed by multiple studies showing that doping with Pt, S or Cu can lead to the formation of local domains with persisting gap and CDW charge modulation, while the backfolded  $\text{Se}_{4p}^*$  band requiring long range order is almost completely suppressed<sup>49-54</sup>. The Jahn-Teller scenario is further corroborated by ultrafast THz experiments reporting a signatures of a residual gap and a periodic lattice distortion even after the excitonic order was completely destroyed, caused by a remaining Jahn-Teller-like CDW<sup>17</sup>. Moreover, the strong coupling of the lattice to the electronic structure is confirmed by oscillations of the  $\text{Se}_{4p}$  valence band position at the frequency of the characteristic Alg phonon mode<sup>19</sup>. The sum of these observations strongly hint towards Jahn-Teller like CDW fluctuations as the reason for the robustness of the gap, however it should be noted that also electron-hole fluctuations<sup>25,55</sup> cannot be completely ruled out. Finally we note that the melting of the CDW state likely occurs in a spatially incoherent way: A previous equilibrium ARPES study<sup>56</sup> found that when decreasing temperature a 2D ( $2 \times 2$ ) CDW order sets in  $\sim 30$  K above the well known 3D ( $2 \times 2 \times 2$ ) structure, indicating a dimensional crossover. Moreover a

recent UED study<sup>36</sup> found that optical excitation above a critical fluence melts the 3D CDW phase while creating a nonequilibrium 2D CDW phase. The structural dynamics probed by UED show noteworthy parallels to the behavior of the gap in the electronic spectrum studied in this work and are a promising topic of further theoretical and experimental investigations.

In conclusion this work places TiSe<sub>2</sub> in the same context of other quantum materials where a pseudogap phase appears to precede long-range order. We find strong indications that the gap in TiSe<sub>2</sub> is governed by two contributions, one caused by an excitonic condensate with long coherence length and one of Jahn-Teller character with short coherence length. The latter contribution can still give a well defined gap even after long range order was destroyed. In contrast, the well studied intensity of the folded Se<sub>4p</sub>\* band gives access to predominantly only one of these contributions and originates mostly from the excitonic order. Thus, in summary our work exemplifies how valuable mechanistic insight can be gained by studying the order parameter and shines new light onto the complicated interplay of long and short range order in TiSe<sub>2</sub>, which is eventually the key for the understanding of doping or pressure induced superconductivity in this and other materials.

## DATA AVAILABILITY

The datasets generated and/or analysed during the current study are not publicly available as they contain additional findings not reported in this manuscript, but are available from the corresponding author on reasonable request.

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**COMPETING INTEREST**

The authors declare no competing financial interest.

**AUTHOR CONTRIBUTIONS**

A.L. designed and supervised the project. Data was collected by M.H. and Y.L. and analyzed by M.H. with help from Y.L., N.D., R.K. and A.L. Samples were provided by R.S. and S.T. The XUV-trARPES setup was designed by R.K. Manuscript preparation was done by M.H. with input from all co-authors.